Supporting Information (SI) for

Oxygen Vacancy Engineering of Self-Doped SnO_{2-x} Nanocrystals for Ultrasensitive NO₂ Detection

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Figure S1. Nitrogen adsorption-desorption isotherms of the SnO_2 and SnO_{2-x} (1:2.5) NCs.



Figure S2. XPS survey spectra of SnO_2 and SnO_{2-x} (1:5) and SnO_{2-x} (1:2.5) NCs.

Table 51. Atomic compositions and atomic fatio (0/51) from Ar 5	Table	S1.	Atomic	compositions	and	atomic ratio	(O/Sn) from XPS
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Samples	Atomic compositions (A	Atomic ratio O/Sn	
	Sn 3d	O 1s	
SnO ₂	33.38	66.62	1.996
SnO _{2-x} (1:5)	34.21	65.79	1.923
SnO _{2-x} (1:2.5)	35.63	64.37	1.807



Figure S3. Dynamic response/recover curves of four repeated cycles at NO_2 concentration of 500 ppb.



Figure S4. Time-resolved DRIFS spectra of SnO_{2-x} (1:5). (a: background in 100 ml/min helium at 100 °C; after adsorption of NO₂ (1.5ppm NO₂ in oxygen and helium) at 100 °C for 0.5, 1, 2, 3, 4, 5 min (b, c, d, e, f, g).)

Materials	NO ₂	Operating	Response	Response	Recovery	Reference
	concentration	temperature		Time(s)	Time(s)	
	(ppm)	(°C)				
NiO/SnO ₂	5	250	4	-	-	1
graphene	6	150	10.5	360	780	2
oxide/SnO ₂						
SnO ₂	2	150	14.2	292	228	3
nanowires						
Ni-doped	20	250	90.3	24s	35s	4
SnO ₂						
nanofiber						
Ln-doped	500	150	72	<2s	-	5
SnO ₂						
Sn ²⁺ Self-	0.5	100	70	230	88	This
Doped SnO _{2-x}						work

Table S2. Comparison of other SnO₂-based sensing performance of NO_2

Table S3. Assignment of vibrational frequencies of adsorbed surface products

Surface species description	v_3 (cm ⁻¹)	v_1 (cm ⁻¹)	Refs
NO_2 (gas)	1628, 1595		6
NO_2 (ads)	1390, 1348		6
Free NO ₃ ⁻ ion	1380		7
Monodentate nitrate	1530-1480 1290-1250	1035-970	7
$(M - O - NO_2)$	1500-1045 1305-1270	1025-990	8
Bidentate nitrate	1565-1500 1300-1260	1040-1010	7
$(M - O_2 NO)$	1630-1475 1300-1160	1040-960	8
	1545-1580 1280	1045	9
Bridging nitrate	1650-1600 1225-1170	1030-1000	7
$((M-O)_2 = NO)$	1520 1290	1008	8
Free NO ₂ - ion	1260	1330	7
Bridging bidentate nitrite $((M-O)_2=N)$	1230-1200	~1330	10,11
Nitro compound $(M-NO_2)$	1440-1335	1350-1315	7
Monodentate nitrite	~1479		10
(M - O - N - O)	\sim 1463		11
Chelating nitro compound	1520-1390	1260-1180	7
(M-O	1510	1175	9
M-N-O			

following the absorption of NO₂ on SnO₂ NCs.

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